NSN 5961-01-115-8782

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-115-8782 **Inclosure Material:** Glass **Overall Length:** 0.160 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.075 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 reverse voltage, peak **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current absolute **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig: A110a0